

KSA542

LOW FREQUENCY AMPLIFIER

- Collector-Base Voltage: V_{CBO}= -30V
 Low Collector-Emitter Saturation Voltage: V_{CE}(sat)= -0.15V(TYP.)
- Complement to KSC184



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

| Symbol | Parameter | Ratings | Units |
|------------------|---------------------------|-----------|-------|
| V _{CBO} | Collector-Base Voltage | -30 | V |
| V _{CEO} | Collector-Emitter Voltage | -25 | V |
| V _{EBO} | Emitter-Base Voltage | -5 | V |
| I _C | Collector Current | -50 | mA |
| P _C | Collector Dissipation | 250 | mW |
| T _J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C |

Electrical Characteristics T_a=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|-------------------------------------------|------|-------|------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | $I_C = -100 \mu A, I_E = 0$ | -30 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _C = -10mA. I _B =0 | -25 | | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | $I_E = -10\mu A. I_C = 0$ | - 5 | | | V |
| I _{CBO} | Collector Cut-off Current | $V_{CB} = -25V, I_{E} = 0$ | | | -100 | nA |
| I _{EBO} | Emitter Cut-off Current | V_{EB} = -3V, I_{C} =0 | | | -100 | nA |
| h _{FE} | DC Current Gain | V_{CE} = -6V, I_{C} = -1mA | 40 | | 400 | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I_C = -20mA, I_B = -2mA | | -0.15 | -0.3 | V |
| V _{BE} (on) | Base-Emitter On Voltage | V_{CE} = -6V, I_{C} = -1mA | | -0.65 | -1.0 | V |
| f _T | Current Gain Bandwidth Product | V_{CE} = -6V, I_{C} = -1mA | | 100 | | MHz |
| C _{ob} | Output Capacitance | $V_{CB} = -6V, I_{E} = 0, f = 1MHz$ | | 2.5 | | pF |

h_{FE} Classification

| Classification | R | 0 | Y | G |
|-----------------|---------|----------|-----------|-----------|
| h _{FE} | 40 ~ 80 | 70 ~ 140 | 120 ~ 240 | 200 ~ 400 |

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Typical Characteristics

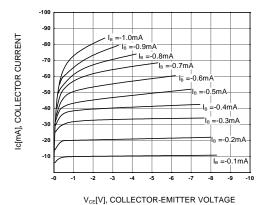
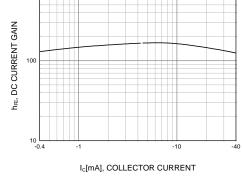


Figure 1. Static Characteristic



1000

V_{CE} = - 6V

Figure 2. DC current Gain

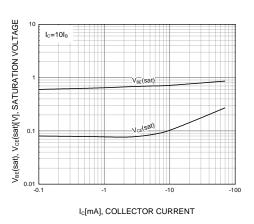


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

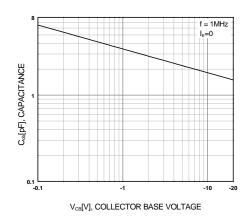


Figure 4. Collector Output Capacitance

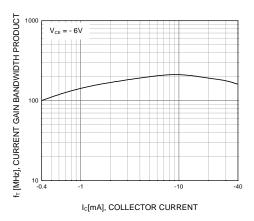
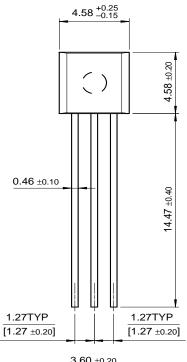


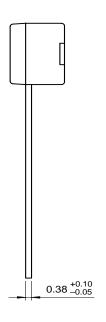
Figure 5. Current Gain Bandwidth Product

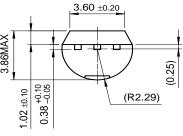
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Package Demensions

TO-92







Dimensions in Millimeters

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